

Features:

- Isolated mounting base 3000V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving

Typical Applications

- Various rectifiers
- DC supply for PWM inverter

V _{RSM}	V _{RRM}	品名
900V	800V	Mx800D80
1100V	1000V	Mx800D100
1300V	1200V	Mx800D120
1500V	1400V	Mx800D140
1700V	1600V	Mx800D160
1900V	1800V	Mx800D180

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min.	Typ.	Max.	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Single side cooled, T _c =100°C	150			800	A
I _{F(RMS)}	RMS forward current		150			1256	A
I _{RRM}	Repetitive peak current	at V _{RRM}	150			40	mA
I _{FSM}	Surge forward current	10ms half sine wave V _R =0.6V _{RRM}	150			22.0	kA
I ² t	I ² t for fusing coordination					2420	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.72	V
r _F	Forward slope resistance					0.18	mΩ
V _{FM}	Peak forward voltage	I _{FM} =3000A	25			1.80	V
R _{th(j-c)}	Thermal resistance Junction to case	D.C. Single side cooled per chip				0.058	°C/W
R _{th(c-h)}	Thermal resistance case to heat sink	D.C. Single side cooled per chip				0.024	°C/W
V _{iso}	Isolation voltage	50Hz,R.M.S,t=1min, I _{iso} :1mA(max)		3000			V
F _m	Terminal connection torque(M12)				14.0		N·m
	Mounting torque(M8)				12.0		N·m
T _{vj}	Junction temperature			-40		150	°C
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight				3240		g
Outline	M07						

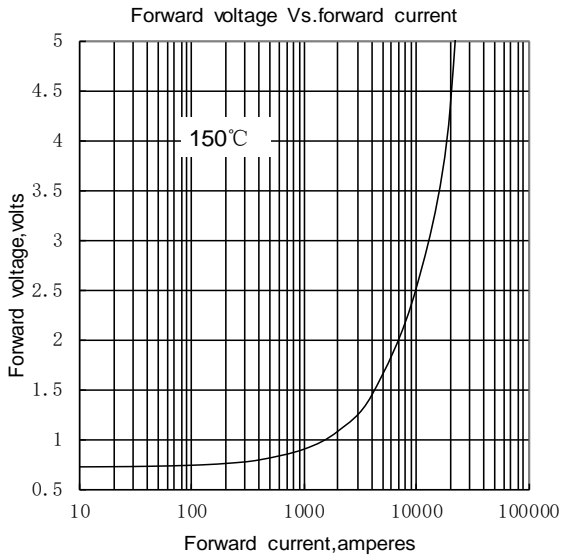


Fig.1

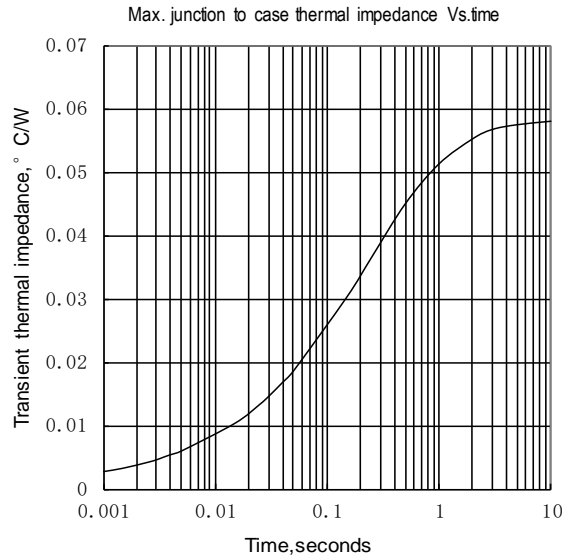


Fig.2

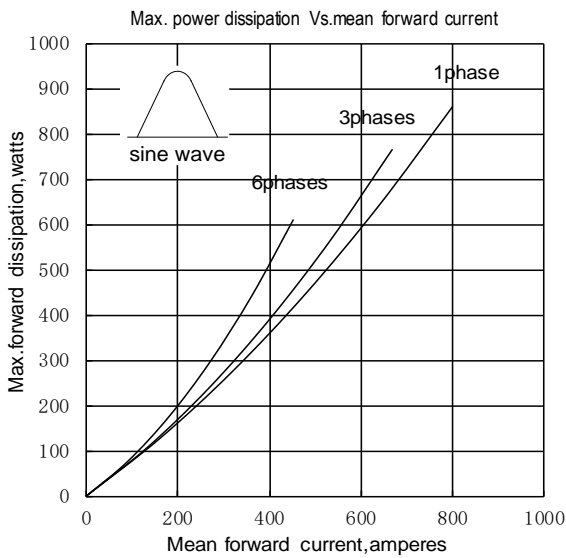


Fig.3

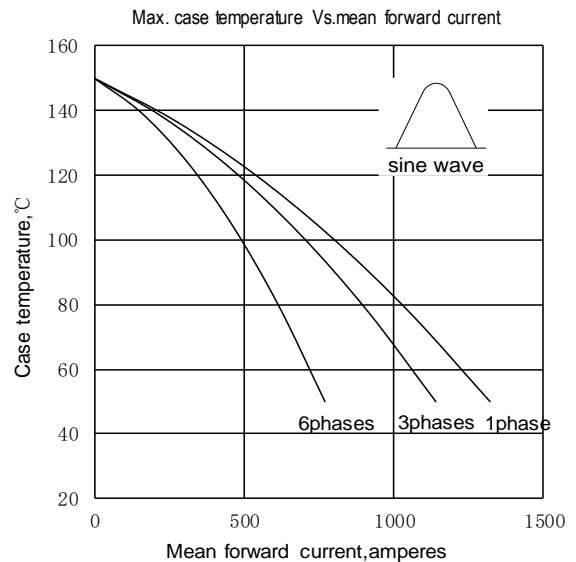


Fig.4

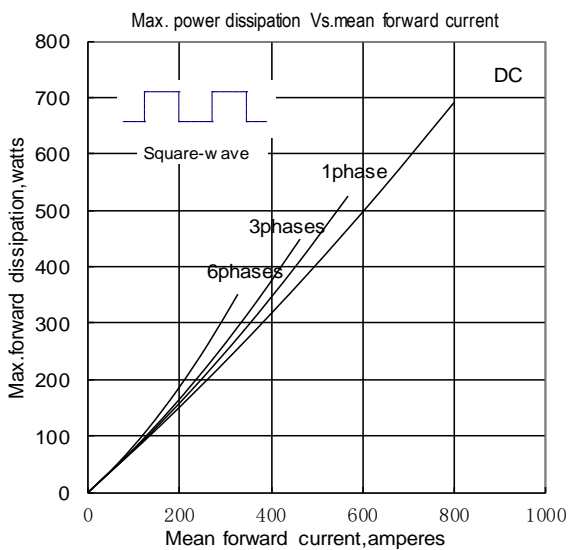


Fig.5

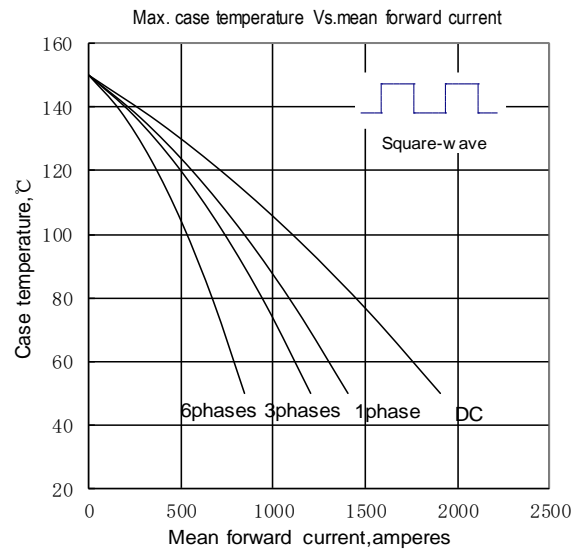


Fig.6

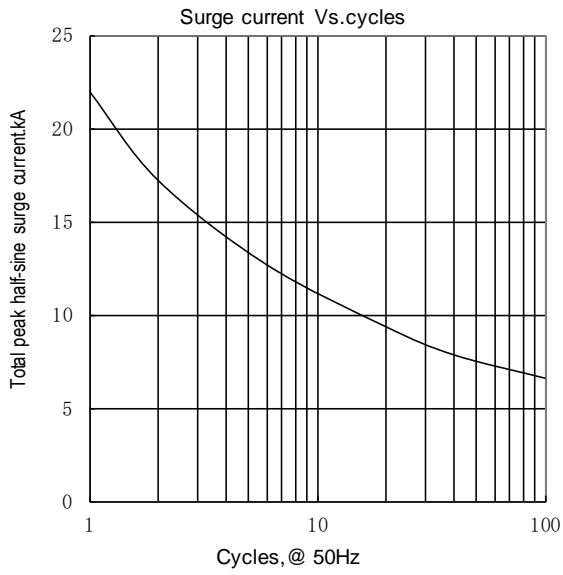
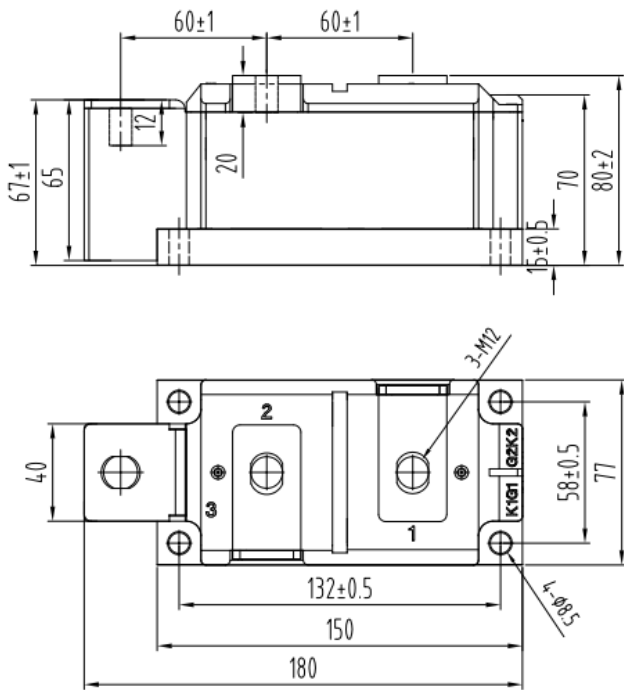
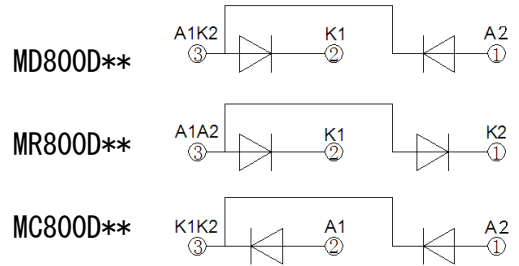


Fig.7



Unmarked dimensional tolerance : ±0.5mm



Nlps reserves the right to change specifications without notice.